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One-Pot Synthesis of Core-Expanded Naphthalene Diimides: Enabling *N*-Substituent Modulation for Diverse n-Type Organic Materials

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ABSTRACT



A mild and versatile one-pot synthesis of core-expanded naphthalene diimides has been developed, which undergoes a nucleophilic aromatic substitution reaction and then an imidization reaction, allowing an easy and low-cost access to diverse n-type organic materials. Some newly synthesized compounds by this one-pot operation exhibited high electron mobility of up to 0.70 cm² V⁻¹ s⁻¹ in ambient conditions.

Naphthalene diimides (NDIs), an important class of π -functional materials, have been widely used in supramolecular chemistry, DNA sensors, artificial photosystems, anion transport, and organic transistors.¹ The development of new NDI-based materials depends on the modification of the NDI core and/or the *N*-substituent. The core substituents can be used to significantly tune the molecular electronic structures of NDIs.^{1b} Some core-substituted NDIs that possess excellent electron-transporting (n-type)

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properties were developed by introducing electron-withdrawing groups (such as CN and halogen atoms)² or electrondonating moieties (such as thiophenes)³ onto the NDI core.

Recently, core-expanded naphthalene diimides fused with two 2-(1,3-dithiol-2-ylidene)malononitrile moieties (NDI-DTYM2) were successfully developed.⁴ The solution-processed n-channel organic thin film transistors (OTFTs) based on these compounds exhibited high electron mobility (0.19–1.2 cm² V⁻¹ s⁻¹) and excellent air/ operating stability,^{4,5} demonstrating that the π -core of

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^{(1) (}a) Bhosale, S. V.; Jani, C. H.; Langford, S. J. *Chem. Soc. Rev.* **2008**, *37*, 331. (b) Sakai, N.; Mareda, J.; Vauthey, E.; Matile, S. *Chem. Commun.* **2010**, *46*, 4225. (c) Zhan, X.; Facchetti, A.; Barlow, S.; Marks, T. J.; Ratner, M. A.; Wasielewski, M. R.; Marder, S. R. *Adv. Mater.* **2011**, *23*, 268. (d) Jung, B. J.; Tremblay, N. J.; Yeh, M.-L.; Katz, H. E. *Chem. Mater.* **2011**, *23*, 568. (e) Würthner, F.; Stolte, M. *Chem. Commun.* **2011**, *47*, 5109.

^{(2) (}a) Jones, B. A.; Facchetti, A.; Marks, T. J.; Wasielewski, M. R. *Chem. Mater.* **2007**, *19*, 2703. (b) Oh, J. H.; Suraru, S.-L.; Lee, W.-Y.; Könemann, M.; Höffken, H. W.; Röger, C.; Schmidt, R.; Chung, Y.; Chen, W.-C.; Würthner, F.; Bao, Z. *Adv. Funct. Mater.* **2010**, *20*, 2148.

^{(3) (}a) Yan, H.; Chen, Z.; Zheng, Y.; Newman, C.; Quinn, J. R.; Dötz, F.; Kastler, M.; Facchetti, A. *Nature* **2009**, *457*, 679. (b) Polander, L. E.; Tiwari, S. P.; Pandey, L.; Seifried, B. M.; Zhang, Q.; Barlow, S.; Risko, C.; Brédas, J.-L.; Kippelen, B.; Marder, S. R. *Chem. Mater.* **2011**, *23*, 3408.

^{(4) (}a) Gao, X.; Di, C.; Hu, Y.; Yang, X.; Fan, H.; Zhang, F.; Liu, Y.; Li, H.; Zhu, D. J. Am. Chem. Soc. **2010**, *132*, 3697. (b) Hu, Y.; Gao, X.; Di, C.; Yang, X.; Zhang, F.; Liu, Y.; Li, H.; Zhu, D. Chem. Mater. **2011**, *23*, 1204.

⁽⁵⁾ Zhao, Y.; Di, C.; Gao, X.; Hu, Y.; Guo, Y.; Zhang, L.; Liu, Y.; Wang, J.; Hu, W.; Zhu, D. *Adv. Mater.* **2011**, *23*, 2448.

Scheme 1. Synthesis of NDI-DTYM2 Derivatives (1) from 2,3,6,7-Tetrabromonaphthalene Dianhydride (2) via Methods A and B with Different Key Features



NDI-DTYM2 is a perfect building block for air-stable electron transport. For rylene and related diimides, N-substituent modulation does not substantially affect the molecular electronic structure⁶ but allows for tuning solubility, molecular aggregation behavior, and molecular packing in the solid state.⁷ Therefore, the N-substituent modulation will play an important role in using the π -core of NDI-DTYM2 to achieve superior n-type organic materials. This will greatly contribute to the development of organic electronics, where one of the biggest challenges is the distinct lack of high-performance, ambient-stable, n-type organic materials.⁸ Moreover, new properties and applications of NDI-DTYM2 derivatives could also be accomplished by N-substituent modulation. Given the significance of N-substituent modulation for NDI-DTY M2 derivatives, an efficient synthetic strategy is highly desirable.

As shown in Scheme 1 (method A), the previously reported synthetic method for symmetrically *N*-substituted NDI-DTYM2 derivatives that attach the swallow-tail

Table 1. Synthesis of NDI-DTYM2 Derivatives (1a-i) via Different Synthetic Methods (A and B)

entry	R ¹ , R ²	yield of 1 (%)
1	$R^1 = R^2 = \frac{C_{10}H_{21}}{C_6H_{17}}$	1a (18) ^a /(28) ^b
2	$R^1 = R^2 = \sqrt{-CC_{12}H_{25}}$	1b (11) ^{<i>a</i>} /(29) ^{<i>b</i>}
3	$R^1 = R^2 = $	$1c - \frac{a.c}{(48)^b}$
4	$\mathbf{R}^1 = \mathbf{R}^2 = \cdots \sqrt{2}$	1d $(trace)^{a}/(55)^{b}$
5	$R^1 = R^2 = \sqrt[4]{OC_8H_{17}} OC_8H_{17}$	$1e(0)^{a}/(42)^{b}$
6	$R^1 = \frac{C_{12}H_{25}}{C_{10}H_{21}}$ $R^2 = \frac{Si(EIO)_3}{Si(EIO)_3}$	$1f(0)^{a}/(13)^{b}$
7	$R^{1} = \frac{1}{C_{8}H_{17}} R^{2} = \frac{1}{C_{8}} + \frac{1}{3} + \frac{1}{3$	1g $(trace)^{a}/(19)^{b}$
8	$R^{1} = \sum_{\substack{C_{10}H_{21}\\H_{21}}} K^{1}$	1h $(trace)^{a}/(21)^{b}$
	R ² =	
9	$R^1 = - C_{10}H_{21} R^2 = $	1i (trace) ^{<i>a</i>} /(20) ^{<i>b</i>}

^{*a*} Isolated total yields achieved by method A. ^{*b*} Isolated yields achieved by method B at 50 °C; the reaction can also be performed at room temperature, but the yield is relatively lower. ^{*c*} Complex mixture of nonseparable products.

alkyl chains suffers from the complex multistep reactions with the low total yields (9–20%), the use of a harsh solvent/reagent (acetic acid/phosphorus tribromide), and a relatively high reaction temperature.^{4,9a} Furthermore, method A could only afford limited types of symmetrically *N*-substituted NDI-DTYM2 derivatives and was not efficient for synthesizing unsymmetrically *N*-substituted molecules. To overcome these drawbacks and to pursue promising low-cost high-performance n-type organic materials, a mild and straightforward synthetic strategy for diverse NDI-DTYM2 derivatives is highly desirable.

Herein, we report a versatile one-pot synthesis of NDI-DTYM2 derivatives, which allows for efficient *N*-substituent modulation. This one-pot operation possesses some noteworthy virtues, such as the efficiency for synthesizing both symmetrically and unsymmetrically *N*-substituted compounds, a fast and straightforward procedure (onepot synthesis, no catalyst used, and no additional reagents required), mildness (reactions can be run between room temperature and 50 °C with DMF as solvent), and wide functional group tolerance (e.g., alkyl, aryl, benzyl, and other functionalized *N*-groups).

^{(6) (}a) Langhals, H.; Demmig, S.; Huber, H. *Spectrochim. Acta A* **1988**, 44A, 1189. (b) Wicklein, A.; Lang, A.; Muth, M.; Thelakkat, M. *J. Am. Chem. Soc.* **2009**, *131*, 14442.

^{(7) (}a) Würthner, F. Chem. Commun. 2004, 1564. (b) Huang, C.; Barlow, S.; Marder, S. R. J. Org. Chem. 2011, 76, 2386. (c) Katz, H. E.; Lovinger, A. J.; Johnson, J.; Kloc, C.; Siegrist, T.; Li, W.; Lin, Y.-Y.; Dodabalapur, A. Nature 2000, 404, 478. (d) Shukla, D.; Nelson, S. F.; Freeman, D. C.; Rajeswaran, M.; Ahearn, W. G.; Meyer, D. M.; Carey, J. T. Chem. Mater. 2008, 20, 7486. (e) Molla, M. R.; Ghosh, S. Chem. Mater. 2011, 23, 95.

^{(8) (}a) Newman, C. R.; Frisbie, C. D.; da Silva Filho, D. A.; Brédas, J.-L.; Ewbank, P. C.; Mann, K. R. *Chem. Mater.* **2004**, *16*, 4436. (b) Anthony, J. E.; Facchetti, A.; Heeney, M.; Marder, S. R.; Zhan, X. *Adv. Mater.* **2010**, *22*, 3876.

As shown in Scheme 1 (method B, 50 °C was chosen as an optimized reaction temperature for this study), the onepot synthesis involves two stages from the starting material 2,3,6,7-tetrabromonaphthalene dianhydride (2):⁹ first the reaction of 2 with 3 equiv of Na₂(i-mnt)¹⁰ (i-mnt = 1,1dicyanoethene-2,2-dithiolate) was performed in DMF at 50 °C for 1 h, and then one (R¹NH₂ and R²NH₂, R¹ = R², 3 equiv vs 2) or two types of amines (R¹NH₂ and R²NH₂, R¹ \neq R², 1.5:1.5 equiv vs 2) were added to the above solution and further stirred for 6 h at 50 °C, affording the target NDI-DTYM2 derivatives.

Compounds 1a-i (Table 1) not only highlight the efficiency and excellent functional group tolerance of the one-pot synthesis (method B) but also provide promising n-type organic materials. Compound 1a has been reported previously,^{4a} and its optimum OTFT devices exhibited electron mobilities as high as $0.55-1.2 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ in ambient.⁵ NDI-DTYM2 derivatives **1b**-i are newly developed compounds. As shown in Table 1 (entries 1 and 2), both methods A and B are applicable to the synthesis of symmetrically N-substituted compounds 1a and 1b that bear the N-alkyl chains and N-benzyl groups, respectively, but the yield achieved by method B is much higher than that obtained by method A (28% vs $18\%^{4a}$ for **1a**, and 29% vs 11% for 1b). Compound 1c, bearing two N-(2aminoethyl)-3,4,5-tris (dodecyloxy)benzamide moieties, could not be obtained by method A due to the complex reactions involved (entry 3). The implementation of method A for the synthesis of 1d (a symmetrically N-substituted compound with 4-ter-butylphenyl N-groups) is also unsuccessful, giving only a trace amount of product (entry 4). Compounds 1e and 1f could not be prepared by method A due to their acid-sensitive N-substituents (entries 5 and 6). Similar to 1f, when trying to synthesize other unsymmetrically N-substituted compounds by method A, the results were so disappointing that we obtained only a trace of the target compounds (Table 1, entries 7-9, 1g-i). Fortunately, the one-pot synthetic method B is very efficient for the synthesis of both symmetrically N-substituted NDI-DTYM2 derivatives (Table 1, entries 1-5, 1a-e, $R^1 = R^2$) and unsymmetrically N-substituted ones (Table 1, entries 6-9, 1f-i, $R^1 \neq R^2$) with moderate yields of 28-55% and 13-21%, respectively.

Encouraged by these results, we started to study the reaction process of the one-pot synthesis. As shown in Scheme 2, the one-pot operation is successful when we first carried out the reaction of **2** and Na₂(i-mnt) in DMF, but it failed when the reaction of **2** with amine (R^1NH_2 and R^2NH_2) in DMF was first performed.¹¹ A proposed mechanism for this one-pot synthesis is that the nucleophilic aromatic substitution (S_NAr) reaction of **2** with Na₂(i-mnt)

Scheme 2. Proposed Reaction Process of the One-Pot Synthesis



in DMF affords the core-expanded naphthalene dianhydride (Scheme 2, 6),¹² and then an imidization reaction of 6 and amine (R^1NH_2 and R^2NH_2) gives the target NDI-DTYM2 derivatives (1). This mild imidization reaction that can operate at low temperature (rt to 50 °C) is fairly scarce for the synthesis of rylene and related diimides.¹³

Compounds 1a-i obtained by the one-pot synthesis were characterized by mass spectroscopy, ${}^{1}H/{}^{13}C$ NMR spectra, elemental analysis, and IR spectra. All compounds except 1d are well soluble in common organic solvents. Thermogravimetric analysis (TGA), UV-vis absorption spectra, and cyclic voltammetry (CV) were carried out to evaluate the thermal, optical, and electrochemical properties of the new compounds 1b-i (see Table S1 and Figures S2-5 for details). 1d exhibits the highest onset decomposition temperature (T_d) of 476 °C, and 1i shows the secondary $T_{\rm d}$ value of 399 °C, which are both higher than those of symmetrically N-substituted NDI-DTYM2 derivatives that bear swallow-tail *N*-alkyl chains (370–389 °C).⁴ The results demonstrate that the thermal stability of NDI-DTYM2 derivatives largely depends on the feature of the N-substituent with the order of bis(N-phenyl) > N-phenyl, N'-alkyl > bis(N-alkyl). Compounds **1b**-i showed similar absorption spectra and cyclic voltammograms with comparable peak values for their end absorptions and redox curves (Figures S3-5). This is due to the electronic decoupling of the NDI-DTYM2 core and the N-substituent.⁶ Compounds 1b-i have comparable low-lying LUMO levels of -4.29 to -4.36 eV calculated from the CV results using ferrocene (-4.8 eV to vacuum) as an internal standard (see Table S1 for details), and this is crucial for realizing electron carrier injection and conduction with ambient stability.14

^{(9) (}a) Gao, X.; Qiu, W.; Yang, X.; Liu, Y.; Wang, Y.; Zhang, H.; Qi, T.; Liu, Y.; Lu, K.; Du, C.; Shuai, Z.; Yu, G.; Zhu, D. *Org. Lett.* **2007**, *9*, 3917. (b) Röger, C.; Würthner, F. *J. Org. Chem.* **2007**, *72*, 8070.

⁽¹⁰⁾ Hatchard, W. R. J. Org. Chem. 1964, 29, 660.

⁽¹¹⁾ The reaction of **2** and amine $(R^1NH_2 \text{ and } R^2NH_2)$ in DMF generates 2,3,6,7-tetrabromo-4,8- $N(R^1)$, $N'(R^2)$ carbamoyl-naphthalene-1,5-diacarboxylic acid (Scheme 2, 4; see ref 9a for details), which is difficult to further react with Na₂(i-mnt) in DMF even at a much elevated temperature due to its weak reactivity.

⁽¹²⁾ Only bilateral core-expanded naphthalene dianhydride 6 was detected by mass spectrometry (Figure S1) during the S_NAr reaction; the unilateral core-expanded compound 5 was not detected probably due to its much higher reactivity with Na₂(i-mnt) than **2**.

^{(13) (}a) Zheng, Q.; Huang, J.; Sarjeant, A.; Katz, H. E. J. Am. Chem. Soc. **2008**, 130, 14410. (b) Tambara, K.; Ponnuswamy, N.; Hennrich, G.; Pantos, G. D. J. Org. Chem. **2011**, 76, 3338. (c) Yuan, Z.; Li, J.; Xiao, Y.; Li, Z.; Qian, X. J. Org. Chem. **2010**, 75, 3007.

^{(14) (}a) Jones, B. A.; Facchetti, A.; Wasielewski, M. R.; Marks, T. J.
J. Am. Chem. Soc. 2007, 129, 15259. (b) Usta, H.; Facchetti, A.; Marks, T. J. Acc. Chem. Res. 2011, 44, 501.



Figure 1. Output and transfer characteristics of an OTFT device based on 1i (a, b), spin coated on OTS-treated SiO₂/Si substrate and annealed at 190 °C.

Compound **1e** is a highly soluble molecule, which, in addition to its acetal-containing flexible *N*-alkyl chains, makes **1e** an easy solution-processable material. Compound **1i** that bears one *N*-alkyl chain and one aromatic phenyl group is a representative molecule for unsymmetrically *N*-substituted NDI-DTYM2 derivatives. Herein, we study the electron-transporting properties of these two new compounds (**1e** and **1i**) by fabricating and testing their solution-processed n-channel OTFTs (see Supporting Information, Table S2 for details). Thin films of **1e** and **1i** were spin-coated on octadecyltrichlorosilane (OTS)-treated SiO₂/Si substrates from their chloroform solution, affording a bottom-gate top-Au-contact device structure. All OTFT devices were measured in air. When annealed at 160 °C, a thin film of **1e** gives a mobility of 0.12 cm^2 V^{-1} s⁻¹, a threshold voltage of 13 V, and a current on/off ratio of 10⁶ (Figure S6 exhibits its output and transfer characteristics). As shown in Figure 1. OTFT devices based on 1i (annealed at 190 °C) show high electron mobilities up to $0.70 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$, with a threshold voltage of 7 V and a current on/off ratio of 10^7 . This is one of the best device performances reported so far for solutionprocessed, ambient-stable, n-type organic materials. Yet, there is still much room for improvement in the performance of 1i-based OTFTs, because the thin-film morphology of **1i** is still insufficient (see Figures S7–9 for details).

In conclusion, a versatile one-pot synthesis of NDI-DTYM2 derivatives has been developed, which undergoes an S_NAr reaction and then an imidization reaction, providing an easy and low-cost access to diverse n-type organic materials. Some newly developed compounds exhibited high electron mobilities up to 0.70 cm² V⁻¹ s⁻¹ in ambient conditions. More importantly, this one-pot synthetic method would afford a more diverse set of NDI-DTYM2 derivatives, which we foresee to have exciting applications in organic electronics.

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Supporting Information Available. General experimental methods, synthesis, and characterizations of compounds 1a-i, and OTFT device fabrication/characterization with semiconductors 1e and 1i. This material is available free of charge via the Internet at http://pubs. acs.org.